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Noble, Jr et al.

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[54] MOSFET WITH RAISED STI ISOLATION SELF-ALIGNED TO THE GATE STACK

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[21] Appl No : 365 729

[21] Appl. No.: **365,729**

[56]

H01L 29/00 [52] **U.S. Cl.** **257/301**; 257/305; 257/397; 257/623

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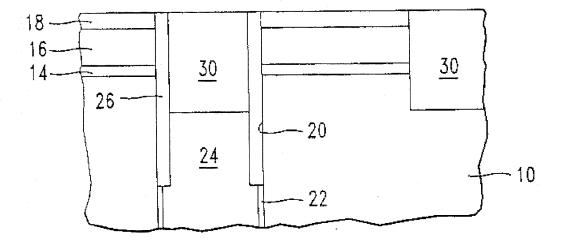
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Primary Examiner—Donald L. Monin, Jr. Attorney, Agent, or Firm—James M. Leas

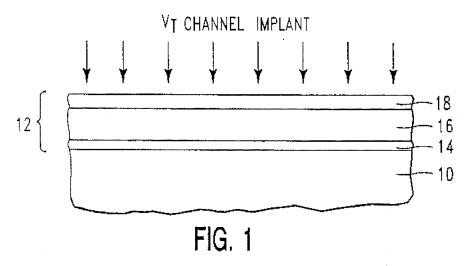
ABSTRACT

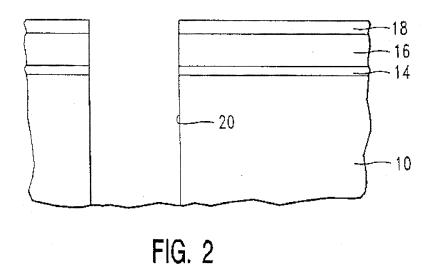
A semiconductor structure comprising a transistor having a gate conductor that has first and second edges bounded by raised isolation structures (e.g. STI). A source diffusion is self-aligned to the third edge and a drain diffusion is self-aligned to the fourth edge of the gate electrode.

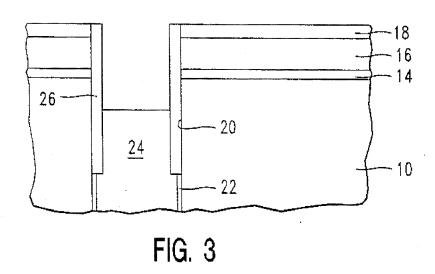
19 Claims, 5 Drawing Sheets



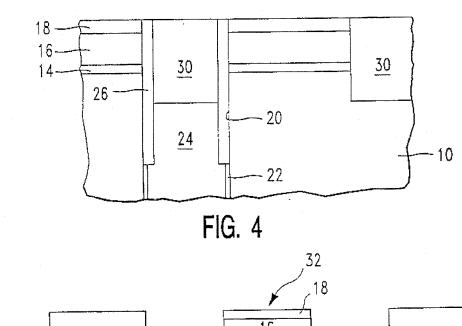












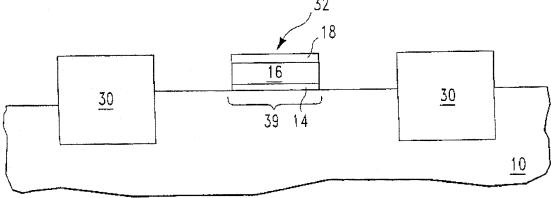


FIG. 5

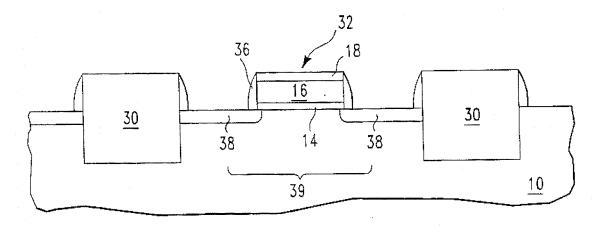


FIG. 6

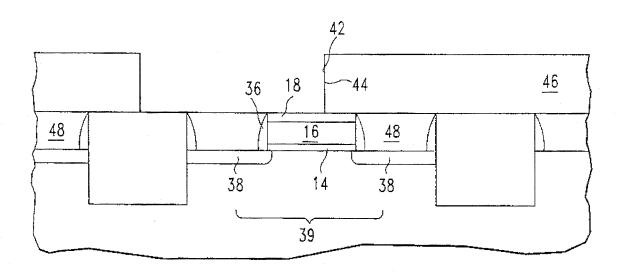


FIG. 7

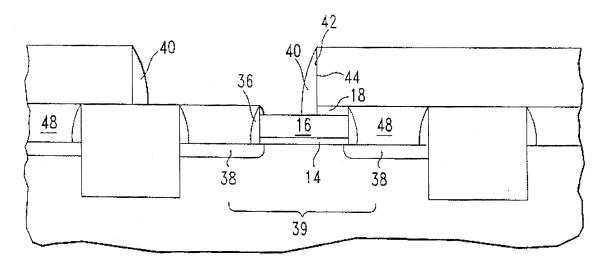


FIG. 8

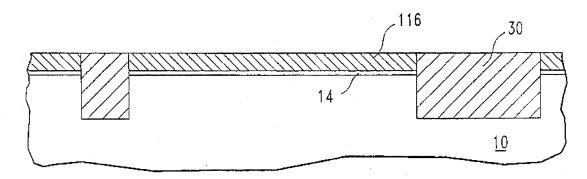


FIG. 9

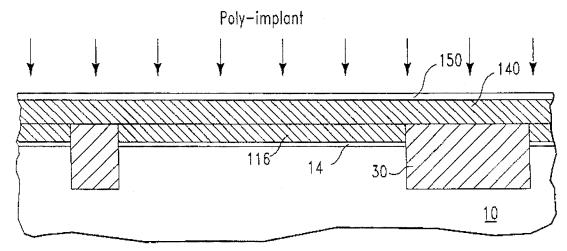
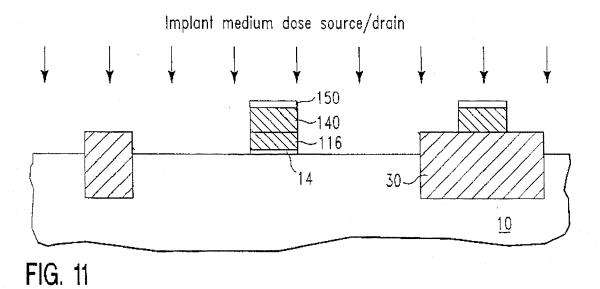


FIG. 10





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